

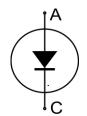
Fast switching diode chip in Emitter Controlled Technology

Features:

- 1200V Emitter Controlled technology
 120 µm chip
- Soft, fast switching
- Low reverse recovery charge
- Small temperature coefficient
- Qualified according to JEDEC for target applications

Recommended for:

 Power modules and discrete devices



Applications:

• SMPS, resonant applications, drives

Chip Type	V _R	<i>I</i> _{Fn}	Die Size	Package
SIDC03D120H8	1200V	3A	1.75 x 1.85 mm ²	sawn on foil

Mechanical Parameters

Die size		1.75 x 1.85		
Area total		3.24		
Anode pad size		1.03 x 1.13		
Thickness		120	μm	
Wafer size		200	mm	
Max. possible chips per wafer		8702		
Passivation frontside		Photoimide		
Pad metal		3200 nm AlSiCu		
Backside metal		Ni Ag – system To achieve a reliable solder connection it is strongly recommended not to consume the Ni layer completely during production process		
Die bond		Electrically conductive epoxy glue and soft solder		
Wire bond		Al, ≤ 500 μm		
Reject ink dot size		Ø 0.65 mm; max 1.2 mm		
Storage environment	for original and sealed MBB bags	Ambient atmosphere air, Temperature 17 °C – 25 °C, < 6 months		
	for open MBB bags	Acc. to IEC62258-3: Atmosphere > 99% Nitrogen or inert gas, Humidity < 25% RH, Temperature 17 °C – 25 °C, < 6 months		



Maximum Ratings

Parameter	Symbol	Condition	Value	Unit
Repetitive peak reverse voltage	V_{RRM}	<i>T</i> _{vj} = 25 °C	1200	V
Continuous forward current	I _F	T _{vj} < 150 °C	1)	Λ.
Maximum repetitive forward current ²⁾	I _{FRM}	T _{vj} < 150 °C	6	A
Junction temperature range	$T_{\rm vj}$		-40+175	°C
Operating junction temperature	$T_{\rm vj}$		-40+150	°C

¹⁾ depending on thermal properties of assembly

Static Characteristics (tested on wafer), $T_{vj} = 25 \, ^{\circ}\text{C}$

Parameter	Symbol	Condition	Value			Unit
			min.	typ.	max.	Oilit
Reverse leakage current	I_{R}	$V_{R} = 1200 V$			27	μA
Cathode-Anode breakdown voltage	V_{BR}	$I_{R} = 0.25 \text{ mA}$	1200			V
Forward voltage drop	V_{F}	$I_{F} = 3A$	1.23	1.6	1.97	

Further Electrical Characteristics

Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

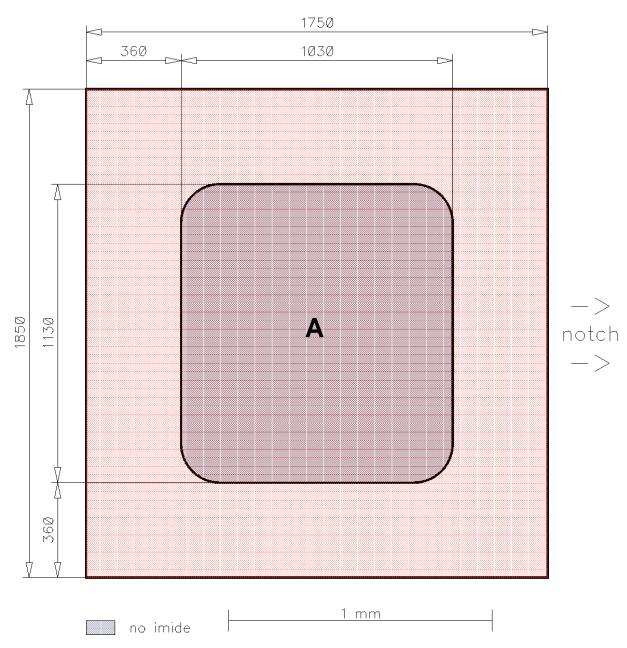
This chip data sheet refers to the device data sheet	
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²⁾ not subject to production test - verified by design/characterisation



Chip Drawing





A: Anode pad

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Bare Die Product Specifics

Test coverage at wafer level cannot cover all application conditions. Therefore it is recommended to test all characteristics which are relevant for the application at package level, including RBSOA and SCSOA.

Description

AQL 0.65 for visual inspection according to failure catalogue

Electrostatic Discharge Sensitive Device according to MIL-STD 883

Revision History

Version	Subject (major changes since last revision)	Date
2.0	Final data sheet	30.12.2014
2.1	Editorial changes	14.10.2015



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